

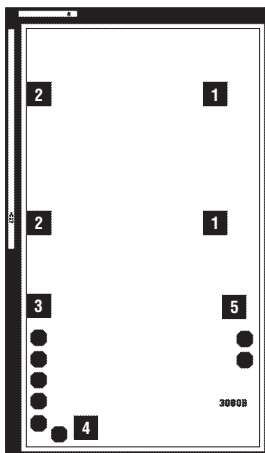
FEATURES

- Outputs May Be Paralleled for Higher Current and Heat Spreading
- Single Resistor Sets Output Voltage
- Output Adjustable to 0V
- 10 μ A SET Pin Current: 1% Initial Accuracy
- Total Ionizing Dose (TID) Tolerance, per TM1019.8, MIL-STD-883 up to:
 - 200kRad (Si), per Condition A, at 50Rads(Si)/sec
 - 100kRad (Si), per Condition D, at 10mRads(Si)/sec
 - ELDRS Pass 100kRad(Si)
- Displacement Damage Defects (DDD) Up to 1E12 Neutrons/cm²
- Single Event Latchup (SEL) Threshold Linear Energy Transfer (LET) $\geq 110\text{MeV}\cdot\text{cm}^2/\text{mg}$ at $T_{\text{CASE}} = 100^\circ\text{C}$
- MIL-PRF-38535 Class V Compliant

DESCRIPTION

The RH3080 is a 0.9A low dropout linear regulator with a unique architecture featuring a precision current source and voltage follower which allows the output to be programmed to any voltage between zero and 36V. Multiple regulators can be paralleled to increase total output current and spread heat over a system PC board with no need for heat sinking. The pass transistor collector can be brought out independently of the circuit supply voltage to allow dropout voltage to approach the saturation limit of the pass transistor. A 2.2 μ F capacitor on the output with an ESR of less than 0.5 Ω is adequate to ensure stability. Applications with large output load transients require a larger output capacitor value to minimize output voltage change. Input circuitry ensures output safe operating area current limiting and thermal shutdown protection. The rated output current of an RH3080-based part is fixed by internal wire length/resistance. Linear Technology dice element evaluations are based on parts rated for 0.9A output current.

DICE PINOUT



44mils x 75mils
Backside metal: Alloyed gold layer
Backside potential: OUT
Tie SENSE to OUT

PAD FUNCTION

1. IN
2. OUT
3. SENSE
4. SET
5. V_{CONTROL}

DIE CROSS REFERENCE

LTC® Finished Part Number	Order Part Number
RH3080MK RH3080MK	RH3080MK DICE RH3080MK DWF*

Please refer to [LT®3080](#) standard product data sheet for other applicable product information.

*DWF = DICE in wafer form.

ABSOLUTE MAXIMUM RATINGS

(Note 1) (All voltages relative to V_{OUT})

V_{CONTROL} Pin Voltage	40V, -0.3V
IN Pin Voltage (Note 11)	40V, -0.3V
SET Pin Current (Note 6)	$\pm 10\text{mA}$
SET Pin Voltage (Relative to OUT, Note 6)	$\pm 0.3\text{V}$
Output Short-Circuit Duration	Indefinite
Operating Junction Temperature Range (Notes 2, 10)	-55°C to 125°C
Storage Temperature Range	-65°C to 150°C

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TABLE 1. DICE/DWF ELECTRICAL TEST LIMITS $T_A = 25^\circ\text{C}$ (Notes 2, 5, 8, 9, 12)

PARAMETER	CONDITIONS	MIN	MAX	UNITS
SET Pin Current (Note 6)	$V_{IN} = 1\text{V}$, $V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 1\text{mA}$	9.9	10.1	μA
Output Offset Voltage ($V_{OUT} - V_{SET}$)	$V_{IN} = 1\text{V}$, $V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 1\text{mA}$	-5	5	mV
Load Regulation, I_{SET}	$I_{LOAD} = 1\text{mA}$ to 100mA	-15	15	nA
Load Regulation, V_{OS}	$I_{LOAD} = 1\text{mA}$ to 100mA	-1.0	1.0	mV
Line Regulation, I_{SET}	$V_{IN} = 1\text{V}$ to 26V , $V_{CONTROL} = 2\text{V}$ to 26V , $I_{LOAD} = 1\text{mA}$	-0.45	0.45	nA/V
Line Regulation, V_{OS}	$V_{IN} = 1\text{V}$ to 26V , $V_{CONTROL} = 2\text{V}$ to 26V , $I_{LOAD} = 1\text{mA}$	-0.05	0.05	mV/V
Minimum Load Current (Note 3)	$V_{IN} = 10\text{V}$, $V_{CONTROL} = 10\text{V}$ $V_{IN} = 26\text{V}$, $V_{CONTROL} = 26\text{V}$		0.4 0.9	 mA
$V_{CONTROL}$ Dropout Voltage (Note 4)	$V_{IN} = 1\text{V}$, $I_{LOAD} = 0.1\text{A}$		1.4	V
V_{IN} Dropout Voltage (Note 4)	$V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 0.1\text{A}$		0.17	V
$V_{CONTROL}$ Pin Current (Note 5)	$V_{IN} = 1\text{V}$, $V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 0.1\text{A}$		5.3	mA

TABLE 2. ELECTRICAL CHARACTERISTICS (Preirradiation) (Notes 2, 9, 12)

PARAMETER	CONDITIONS	$T_A = 25^\circ\text{C}$		SUB-GROUP	$-55^\circ\text{C} < T_A < 125^\circ\text{C}$		SUB-GROUP	UNITS
		MIN	MAX		MIN	MAX		
SET Pin Current (Note 6)	$V_{IN} = 1\text{V}$, $V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 1\text{mA}$	9.9	10.1	1	9.8	10.2	2, 3	μA
Output Offset Voltage ($V_{OUT} - V_{SET}$)	$V_{IN} = 1\text{V}$, $V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 1\text{mA}$	-5	5	1	-6	6	2, 3	mV
Load Regulation, I_{SET}	$I_{LOAD} = 1\text{mA}$ to 0.9A	-15	15	1	-30	30	2, 3	nA
Load Regulation, V_{OS}	$I_{LOAD} = 1\text{mA}$ to 0.9A	-1.0	1.0	1	-1.5	1.5	2, 3	mV
Line Regulation, I_{SET} (Note 11)	$V_{IN} = 1\text{V}$ to 26V , $V_{CONTROL} = 2\text{V}$ to 26V , $I_{LOAD} = 1\text{mA}$	-0.45	0.45	1	-0.6	0.6	2, 3	nA/V
Line Regulation, V_{OS} (Note 11)	$V_{IN} = 1\text{V}$ to 26V , $V_{CONTROL} = 2\text{V}$ to 26V , $I_{LOAD} = 1\text{mA}$	-0.05	0.05	1	-0.06	0.06	2, 3	mV/V
Minimum Load Current (Notes 3, 11)	$V_{IN} = 10\text{V}$, $V_{CONTROL} = 10\text{V}$		0.4	1		0.6	2, 3	mA
	$V_{IN} = 26\text{V}$, $V_{CONTROL} = 26\text{V}$		0.9	1		1	2, 3	mA
$V_{CONTROL}$ Dropout Voltage (Note 4)	$V_{IN} = 1\text{V}$, $I_{LOAD} = 0.1\text{A}$		1.4	1		1.5	2, 3	V
	$V_{IN} = 1\text{V}$, $I_{LOAD} = 0.5\text{A}$		1.5	1			2, 3	V
	$V_{IN} = 1\text{V}$, $I_{LOAD} = 0.9\text{A}$		1.5	1		1.7	2, 3	V
V_{IN} Dropout Voltage (Note 4)	$V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 0.1\text{A}$		0.17	1		0.2	2, 3	V
	$V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 0.5\text{A}$		0.27	1			2, 3	V
	$V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 0.8\text{A}$		0.45	1		0.6	2, 3	V
$V_{CONTROL}$ Pin Current (Note 5)	$V_{IN} = 1\text{V}$, $V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 0.1\text{A}$		5.3	1		6.3	2, 3	mA
	$V_{IN} = 1\text{V}$, $V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 0.9\text{A}$		22	1		30	2, 3	mA
Current Limit	$V_{IN} = 5\text{V}$, $V_{CONTROL} = 5\text{V}$, $V_{SET} = 0\text{V}$, $V_{OUT} = -0.1\text{V}$	0.9		1	0.9		2, 3	A
Error Amplifier RMS Output Noise (Note 7)	$I_{LOAD} = 0.9\text{A}$, $10\text{Hz} \leq f \leq 100\text{kHz}$, $C_{OUT} = 10\mu\text{F}$, $C_{SET} = 0.1\mu\text{F}$	TYP = 40		1				μV_{RMS}
Reference Current RMS Output Noise (Note 7)	$10\text{Hz} \leq f \leq 100\text{kHz}$	TYP = 1		1				nA _{RMS}

TABLE 3. ELECTRICAL CHARACTERISTICS (Postirradiation) (Notes 2, 9, 12)

PARAMETER	CONDITIONS	10KRads(Si)		20KRads(Si)		50KRads(Si)		100KRads(Si)		200KRads(Si)		UNITS
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
SET Pin Current (Note 6)	$V_{IN} = 1V$, $V_{CONTROL} = 2V$, $I_{LOAD} = 1mA$	9.8	10.2	9.8	10.2	9.8	10.3	9.8	10.4	9.8	10.5	μA
Output Offset Voltage ($V_{OUT} - V_{SET}$)	$V_{IN} = 1V$, $V_{CONTROL} = 2V$, $I_{LOAD} = 1mA$	-8	8	-8	8	-8	8	-9	9	-10	10	mV
Load Regulation, I_{SET}	$I_{LOAD} = 1mA$ to 0.9A	-15	15	-15	15	-25	25	-25	25	-25	25	nA
Load Regulation, V_{OS}	$I_{LOAD} = 1mA$ to 0.9A	-1.25	1.25	-1.3	1.3	-1.35	1.35	-1.4	1.4	-1.5	1.5	mV
Line Regulation, I_{SET}	$V_{IN} = 1V$ to 26V, $V_{CONTROL} = 2V$ to 26V, $I_{LOAD} = 1mA$	-0.8	0.8	-0.8	0.8	-0.9	0.9	-0.9	0.9	-1	1	nA/V
Line Regulation, V_{OS}	$V_{IN} = 1V$ to 26V, $V_{CONTROL} = 2V$ to 26V, $I_{LOAD} = 1mA$	-0.06	0.06	-0.08	0.08	-0.1	0.1	-0.15	0.15	-0.2	0.2	mV/V
Minimum Load Current (Note 3)	$V_{IN} = 10V$, $V_{CONTROL} = 10V$		0.4		0.4		0.4		0.4		0.4	mA
	$V_{IN} = 26V$, $V_{CONTROL} = 26V$		0.9		0.9		0.9		0.9		0.9	mA
$V_{CONTROL}$ Dropout Voltage (Note 4)	$V_{IN} = 1V$, $I_{LOAD} = 0.1A$		1.5		1.5		1.55		1.6		1.65	V
	$V_{IN} = 1V$, $I_{LOAD} = 0.9A$		1.5		1.5		1.55		1.6		1.65	V
V_{IN} Dropout Voltage (Note 4)	$V_{CONTROL} = 2V$, $I_{LOAD} = 0.1A$		0.2		0.21		0.23		0.25		0.3	V
	$V_{CONTROL} = 2V$, $I_{LOAD} = 0.8A$		0.5		0.51		0.53		0.55		0.6	V
CONTROL Pin Current (Note 5)	$V_{IN} = 1V$, $V_{CONTROL} = 2V$, $I_{LOAD} = 0.1A$		5.3		5.3		5.3		5.3		5.3	mA
	$V_{IN} = 1V$, $V_{CONTROL} = 2V$, $I_{LOAD} = 0.9A$		22		22		22		22		22	mA
Current Limit	$V_{IN} = 5V$, $V_{CONTROL} = 5V$, $V_{SET} = 0V$, $V_{OUT} = -0.1V$	0.9		0.9		0.9		0.9		0.9		A
Error Amplifier RMS Output Noise (Note 7)	$I_{LOAD} = 0.9A$, $10Hz \leq f \leq 100kHz$, $C_{OUT} = 10\mu F$, $C_{SET} = 0.1\mu F$	TYP = 40		TYP = 40		TYP = 40		TYP = 40		TYP = 40		μV_{RMS}
Reference Current RMS Output Noise (Note 7)	$10Hz \leq f \leq 100kHz$	TYP = 1		TYP = 1		TYP = 1		TYP = 1		TYP = 1		nA _{RMS}

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: Unless otherwise specified, all voltages are with respect to V_{OUT} . The RH3080MK DICE is tested and specified under pulse load conditions such that $T_J \approx T_A$.

Note 3: Minimum load current is equivalent to the quiescent current of the part. Since all quiescent and drive current is delivered to the output of the part, the minimum load current is the minimum current required to maintain regulation.

Note 4: Dropout results from either of minimum control voltage, $V_{CONTROL}$, or minimum input voltage, V_{IN} , both specified with respect to V_{OUT} . These specifications represent the minimum input-to-output differential voltage required to maintain regulation.

Note 5: The $V_{CONTROL}$ pin current is the drive current required for the output transistor. This current tracks output current with roughly a 1:60 ratio. The minimum value is equal to the quiescent current of the device.

Note 6: SET pin is clamped to the output with diodes. These devices only carry current under transient overloads.

Note 7: Adding a small capacitor across the reference current resistor lowers output noise. Adding this capacitor bypasses the resistor shot noise and reference current noise; output noise is then equal to error amplifier noise (see LT3080 data sheet and Application Note AN83).

Note 8: Dice are probe tested at 25°C to the limits shown in Table 1. Except for high current tests, dice are tested under low current conditions which assure full load current specifications when assembled.

Note 9: Dice that are not qualified by Linear Technology with a can sample are guaranteed to meet specifications of Table 1 only. Dice qualified by Linear Technology with a can sample meet specifications in all tables.

Note 10: This IC includes overtemperature protection that is intended to protect the device during momentary overload conditions. Junction temperature exceeds the maximum operating junction temperature when overtemperature protection is active. Continuous operation above the specified maximum operating junction temperature may impair device reliability.

Note 11: Current limit may decrease to zero at input-to-output differential voltages ($V_{IN} - V_{OUT}$) greater than 26V. Operation at voltages for both I_N and $V_{CONTROL}$ is allowed up to a maximum of 36V as long as the difference between input and output voltage is below the specified differential ($V_{IN} - V_{OUT}$) voltage. Line and load regulation specifications are not applicable when the device is in current limit.

Note 12: Please refer to LT3080 standard product data sheet for Typical Performance Characteristics, Pin Functions, Applications Information and Typical Applications.

TABLE 4. POST BURN-IN ENDPOINTS AND DELTA LIMIT REQUIREMENTS $T_A = 25^{\circ}\text{C}$

PARAMETER	CONDITIONS	ENDPOINT LIMITS		DELTA LIMITS		UNITS
		MIN	MAX	MIN	MAX	
SET Pin Current (Note 6)	$V_{IN} = 1\text{V}$, $V_{CONTROL} = 2\text{V}$, $I_{LOAD} = 1\text{mA}$	9.9	10.2	-0.1	0.1	μA

TABLE 5. ELECTRICAL TEST REQUIREMENTS

MIL-STD-883 TEST REQUIREMENTS	SUBGROUP
Final Electrical Test Requirements (Method 5004)	1*, 2, 3
Group A Test Requirements (Method 5005)	1, 2, 3
Group B and D for Class S, End Point Electrical Parameters (Method 5005)	1, 2, 3

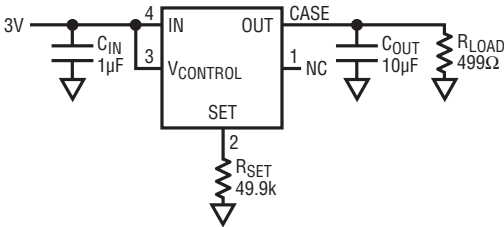
*PDA applies to subgroup 1. See PDA Test Notes.

PDA Test Notes

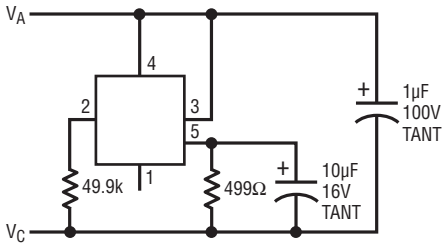
The PDA is specified as 5% based on failures from Group A, Subgroup 1, tests after cooldown as the final electrical test in accordance with method 5004 of MIL-STD-883. The verified failures of Group A, Subgroup 1, after burn-in divided by the total number of devices submitted for burn-in in that lot shall be used to determine the percent for the lot.

Linear Technology Corporation reserves the right to test to tighter limits than those given.

TOTAL DOSE BIAS CIRCUIT

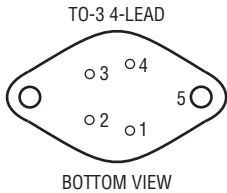


BURN-IN CIRCUIT



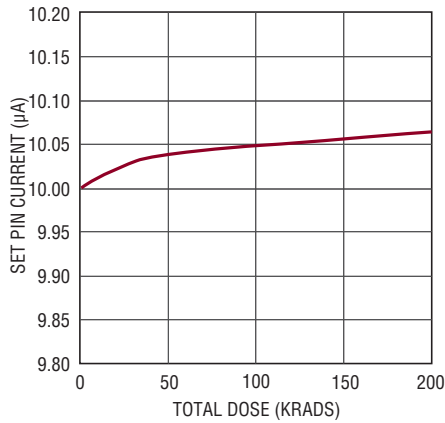
$V_A = V_5 = 24.5\text{V TO } 26.5\text{V}$
 $V_C = \text{GROUND}$
 $T_A = 125^{\circ}\text{C}$
 $T_{J\text{MAX}} = 135^{\circ}\text{C}$
THERMAL SHUTDOWN = $160 \pm 10^{\circ}\text{C}$
DUT CURRENT = 1mA

- 1. NC
- 2. SET
- 3. $V_{CONTROL}$
- 4. IN
- 5. OUT = CASE

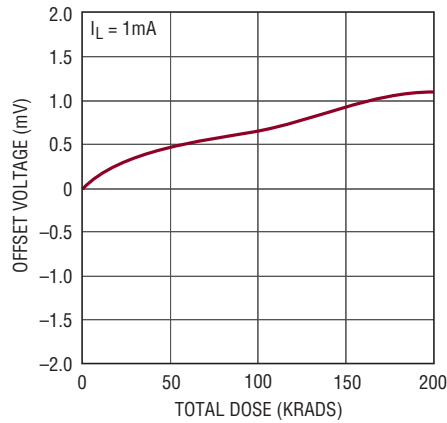


TYPICAL PERFORMANCE CHARACTERISTICS

SET Pin Current

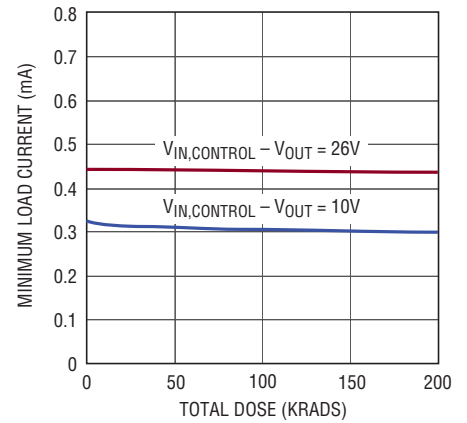


RH3080 G01

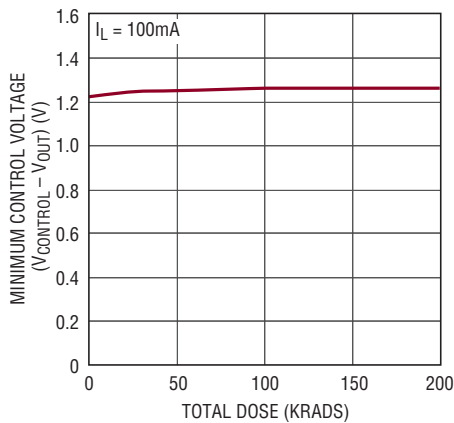
Offset Voltage ($V_{\text{OUT}} - V_{\text{SET}}$)

RH3080 G02

Minimum Load Current

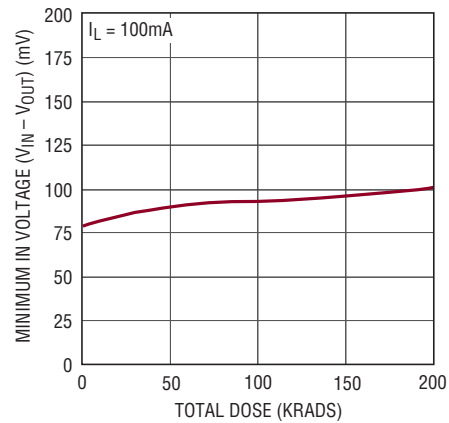


RH3080 G03

Dropout Voltage (Minimum V_{CONTROL} Pin Voltage)

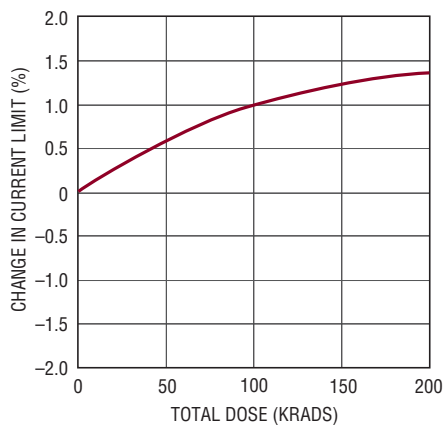
RH3080 G04

Dropout Voltage (Minimum IN Voltage)



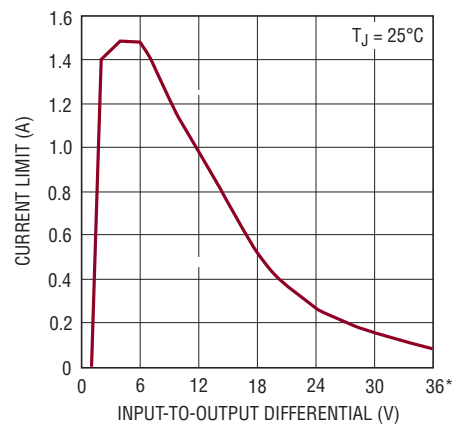
RH3080 G05

Current Limit



RH3080 G06

Current Limit



*SEE NOTE 11 IN ELECTRICAL CHARACTERISTICS TABLE

3080 G07

RH3080MK DICE/DWF

REVISION HISTORY (Revision history begins at Rev B)

REV	DATE	DESCRIPTION	PAGE NUMBER
B	10/14	V_{CONTROL} Pin Current, $I_{\text{LOAD}} = 0.9\text{A}$; Line Reg $I_{\text{SET}}/V_{\text{OS}}$ $V_{\text{CONTROL}} = 2\text{V}$ to 26V , added Notes 11, 12	1, 2, 3
C	05/15	$V_A = V_5 = 24.5\text{V}$ to 26.5V	4

ID 66-13-3080

rh3080mkfc